HAL open science

Morphology of a Self-Doped Conducting Oligomer for Green Energy Applications

Juan Felipe Franco-Gonzalez, Eleni Pavlopoulou, Eleni Stavrinidou, Roger Gabrielsson, Daniel Simon, Magnus Berggren, Igor V Zozoulenko

To cite this version:

Juan Felipe Franco-Gonzalez, Eleni Pavlopoulou, Eleni Stavrinidou, Roger Gabrielsson, Daniel Simon, et al.. Morphology of a Self-Doped Conducting Oligomer for Green Energy Applications. Nanoscale, 2017, 9 (36), pp.13717-13724. 10.1039/x0xx00000x . hal-02888903

HAL Id: hal-02888903

https://hal.science/hal-02888903v1

Submitted on 3 Jul 2020

HAL is a multi-disciplinary open access archive for the deposit and dissemination of scientific research documents, whether they are published or not. The documents may come from teaching and research institutions in France or abroad, or from public or private research centers.

L'archive ouverte pluridisciplinaire **HAL**, est destinée au dépôt et à la diffusion de documents scientifiques de niveau recherche, publiés ou non, émanant des établissements d'enseignement et de recherche français ou étrangers, des laboratoires publics ou privés.

Please do not adjust margins

Full Paper

Morphology of a Self-Doped Conducting Oligomer for Green Energy Applications

Juan Felipe Franco-Gonzalez,[a] Eleni Pavlopoulou,[b] Eleni Stavrinidou,[a] Roger Gabrielsson,[a] Daniel T. Simon,[a] Magnus Berggren[a] and Igor V. Zozoulenko[a]

A recently synthesized self-doped conducting oligomer, salt of bis[3,4-ethylenedioxythiophene]3thiophene butyric acid, ETE-S, is a novel promising material for green energy applications. Recently, it has been demonstrated that it can polymerize *in vivo,* in plant systems, leading to a formation of long-range conducting wires, charge storage and supercapacitive behaviour of living plants. Here we investigate the morphology of ETE-S combining the experimental characterisation using Grazing Incidence Wide Angle X-ray Scattering (GIWAXS) and atomistic molecular dynamics (MD) simulations. The GIWAXS measurements reveal a formation of small crystallites consisting of π-π stacked oligomers (with the staking distance 3.5Å) that are further organized in *h00* lamellae. These experimental results are confirmed by MD calculations, where we calculated the X-ray diffraction pattern and the radial distribution function for the distance between ETE-S chains. Our MD simulations also demonstrate the formation of the percolative paths for charge carriers that extend throughout the whole structure, despite the fact that the oligomers are short (6-9 rings) and crystallites are thin along the π-π stacking direction, consisting of only two or three π-π stacked oligomers. The existence of the percolative paths explains the previously observed high conductivity in *in-vivo* polymerized ETE-S. We also explored the geometrical conformation of ETE-S oligomers and the bending of their aliphatic chains as a function of the oligomer lengths.

1. Introduction

Organic conducting polymers have been used in bioelectronics engineering due to their biocompatibility and flexibility during procesing[1]. Also, in contrast to conventional semiconducting materials, conducting polymers support the transport of both electrons and ions[2]. This makes it possible to use conductive polymers in a variety of biomedical applications requiring the electrical stimuli and control of living tissues, such as neural probes to record neuronal activities[3, 4], biosensors[5, 6], implantable drug delivery devices[7] and others[8]. In the recent years, a concept of electronic plants (*e*-plants) has emerged where the conducting polymers have been integrated inside the vascular tissues of plants forming digital circuits and enabling energy storage [9, 10].

Among all conducting polymers the poly(3,4-ethylenedioxythiophene) (PEDOT) and its derivatives are by far the most used ones in bioelectronics representing the material of choice for many applications.[1, 3, 11] High conductivity of PEDOT is achieved in a doped state, where positive charges in the polymer backbone are compensated by negative counterions. The latter can be whether polymeric counterions, most commonly polystyrenesulfonate (PEDOT:PSS), or molecular counterions such as tosylate (PEDOT:TOS). Alternatively, positive charges in conducting polymers can be induced by self-doping via e.g. a covalently bound anionic side group, as for the case of a self-doped polymer, namely poly(4-(2,3-dihydrothieno [3,4-b]-[1,4]dioxin-2-yl-methoxy)-1-butanesulfonic acid, sodium salt), PEDOT-S[9].

Integration of conducting polymers within living tissue represents a significant technological challenge. *In vivo* electropolymerization of EDOT has been efficiently implemented in the manufacture of neural probes[11]. Recently the self-doped polymer PEDOT-S was distributed in the vascular tissue of a plant and self-organized forming conducting wires[9]. However, the electronic functionality using PEDOT-S could only be achieved in localized areas of plants limited to stems. This limitation has been recently overcome by replacing PEDOT-S with another derivative of PEDOT, namely self-doped oligomer sodium salt of bis[3,4-ethylenedioxythiophene]3thiophene butyric acid (ETE-S)[10], see Figure 1a for its monomeric chemical structure. It has been

[a.] *Laboratory of Organic Electronics, Department of Science and Technology, Linköping University, SE-601 74 Norrköping, Sweden.*
[b.] *Bordeaux INP, Université de Bordeaux, CNRS, LCPO UMR 5629, 33600 Pessac, France.*

† Footnotes relating to the title and/or authors should appear here.
Electronic Supplementary Information (ESI) available: [details of any supplementary information available should be included here]. See DOI: 10.1039/x0xx00000x

Please do not adjust margins

Please do not adjust margins

demonstrated that ETE-S, in contrast to PEDOT-S, is effectively distributed and polymerized through the entire xylem vascular tissue with the plant acting as the template and catalyst for the *in vivo* polymerization reaction. The resulting plant functionalized with ETE-S has shown to operate as an *in vivo* supercapacitor with energy stored in a living plant.

The advances in templating electronic functionality in bioelectronic systems using ETE-S strongly motivate detailed studies of electronic, structural and morphological properties of these materials. Recently, spectroelectrochemical studies of ETE-S were reported focussing on the optical properties and nature of charge carriers in this material[12]. At the same time, its morphology remains practically unexplored. Given that further functionalization of this material and the device development and optimization are difficult without solid understanding of the basic material properties, in this study we perform theoretical modelling of ETE-S morphology using atomistic molecular dynamics simulation combined with experimental characterization using Grazing Incidence Wide Angle X-ray Scattering (GIWAXS).

The self-doped polymers have attracted significant attention during last decades. Experimental studies such as Nuclear Magnetic Resonance (NMR), X-ray Photoelectron Spectroscopy, Ulta-violet Spectroscopy and Electron Paramagnetic Resonance have been used to characterize their structure[13-15]. Additionally, Transmission Electron Microscopy and Scanning Electron Microscopy have been used to characterize their morphology in solar cells applications[15, 16]. It is noteworthy that ab-initio[17, 18] and molecular dynamics (MD) simulations[19-22] have been recently performed for Poly(3-hexylthiophene-2,5-diyl) (P3HT), a polymer with a structure similar to ETE-S. It should be stressed however that P3HT is not a self-doped conducting polymer, and its morphology is very different from that of ETE-S. MD simulations of morphology of doped conducting polymers have been recently performed for the case of molecular counterions for PEDOT:TOS[23], but we are not aware of any theoretical simulation of the morphology of self-doped conducting polymers or oligomers. We therefore hope that our simulations will shed light on the atomistic structure and morphology of self-doped oligomers on sub- and nanometer scales, as well as will motivate further theoretical studies of self-doped oligomers and polymers.

2. Methods

A computational methodology previously published by the authors[23] was implemented in the present work in order to investigate the crystallization of ETE-S in an aqueous solution and in the oligomer cast film.

Ab initio calculations. In order to account for the localized nature of charge carriers in ETE-S, we calculated the partial charges on each atom using first-principles density-functional theory (DFT) with the functional WB97XD[24] and the 6-31+g(d) basis set[25] as implemented in Gaussian package[26]. The partial charge per atom was taken from the fitting to electrostatic potential (ESP)[27] population analysis as implemented in Gaussian suite[26].

Molecular Dynamics Simulations. The General AMBER Force Field (GAFF)[28] was used by employing the moltemplate code[29]. Simulations were carried out with Large-scale Atomic/Molecular Massively Parallel Simulator (LAMMPS) software suite[30]. Water molecules were described by a model of SPC/E[31]. ETE-S chains and water molecules were randomly placed in a computational box of a typical size of 10×10×10 nm^3, using a script written in-house. This simulation box on the average contained ≈100,000 atoms. The system was then minimized and equilibrated by 30 ns run of canonical *NVT* (at 293.15 K) ensemble using the Nose-Hoover thermostat[32-34] and the time integration method of Verlet[35]. Then, water was consecutively removed in 8 steps, such as the water concentration was reduced from 83.3% w.t. (initial solution) to 71.3% w.t., 62.4% w.t., 45.3% w.t., 29.3% w.t., 17.2% w.t. and 13.0% w.t. The system was equilibrated in each step by a *NpT* (at 1 atm and 293.15 K) ensemble for 10 ns run with both barostat and thermostat as Nose-Hoover[32-34]. The radial distribution functions $g(r)$ were calculated as implemented in GROMACS package[36]. X-ray diffraction patterns were simulated as described by Coleman et al.[37] and implemented in LAMMPS suite [30].

Synthesis of ETE-S oligomer. The synthesis of the ETE-S has been performed as described in Ref. [10].

Solution cast film preparation. Fresh solution of ETE-S in deionized water, 1mg/ml was prepared in a vial. The solution was left in room temperature within the vial with the lid open. After 48 hours, polymerization has occurred due to air oxidation and the solution was drop cast on glass substrate and let to dry at room temperature to form a film.

GIWAXS measurements. The structure of the polymerized ETE-S films was probed by Grazing Incidence Wide Angle X-ray Scattering (GIWAXS) experiments that were performed on the Dutch-Belgian Beamline (DUBBLE CRG), station BM26B, at the European Synchrotron Radiation Facility (ESRF), Grenoble, France[38]. The wavelength of the X-rays, λ, was 1.033 Å while the sample-to-detector distance and the angle of incidence, α_i, were set at 17 cm and 0.15°, respectively. The diffracted intensity was recorded by a Frelon CCD camera and was normalized by the incident photon flux and the acquisition time (30s). Flat field, polarization, solid angle and efficiency corrections were subsequently applied to the 2D GIWAXS images. The scattering vector q was defined with respect to the center of the incident beam and has a magnitude of $q=(4\pi/\lambda)\sin(\theta)$, where 2θ is the Bragg reflection angle. Herein we opted to present the wedge-shaped corrected images where q_r and q_z are the in-plane and near out-of-plane scattering vectors, respectively. The scattering vectors are defined as follows: $q_x=(2\pi/\lambda)(\cos(2\theta_f)\cos(\alpha_f)-\cos(\alpha_i))$, $q_y=(2\pi/\lambda)(\sin(2\theta_f)\cos(\alpha_f))$, $q_z = (2\pi/\lambda)(\sin(\alpha_f)+\sin(\alpha_i))$, $q_r^2 = q_x^2 + q_y^2$ where α_f is the exit angle in the vertical direction and

Please do not adjust margins

Please do not adjust margins

$2\theta_f$ is the in-plane scattering angle[30]. Therefore, the scattering vector is calculated as follows, $q^2 = q_r^2 + q_z^2$.

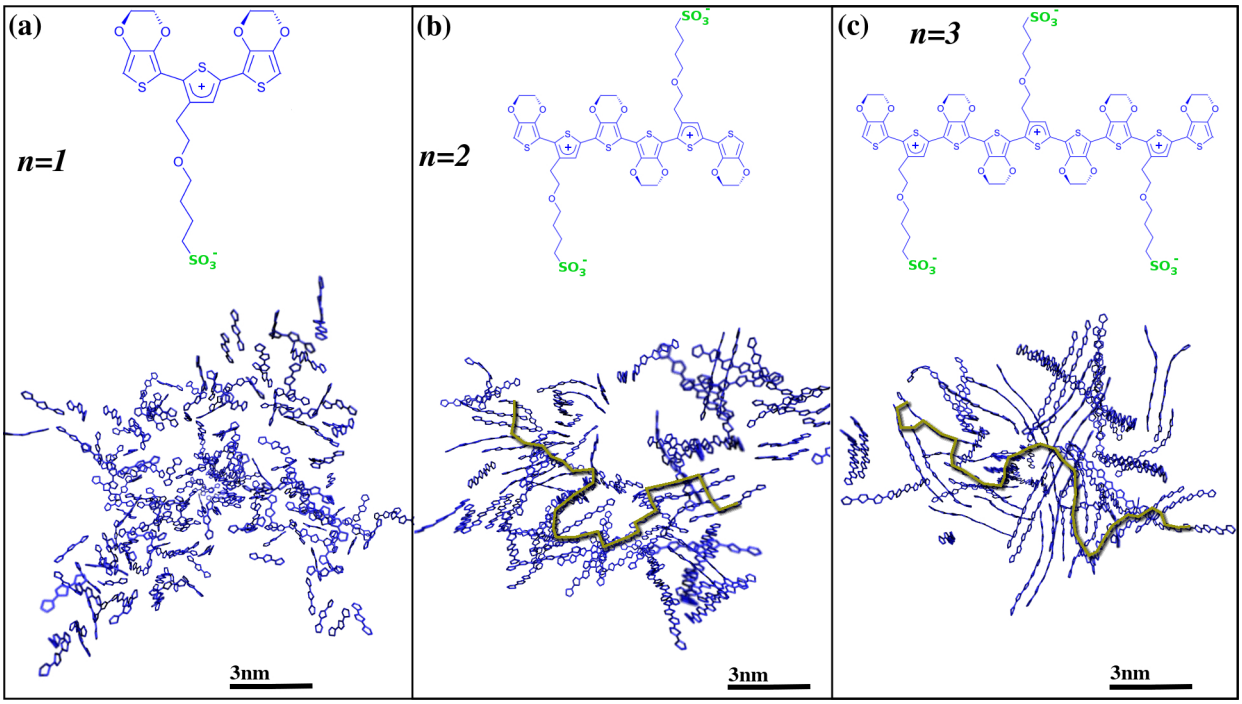

Figure 1. (a)-(c) *Upper*. Schematic representation of self-doped oligomer ETE-S chains for *n*=1,2 and 3. Positive charges in the backbone +*ne* is compensated by negative charges –*e* in each sulfonate group. *Below*. Snapshots of the aqueous ETE-S solution for different chain length *n*=1, 2 and 3; water content is 29.3% w.t. (Only thiophene rings from ETE-S chains are showed for clarity; water is not displayed). Representative percolative paths for charge carriers between ETE-S chains are indicated in green. (Percolative paths are defined as the paths that connect neighboring thiophene rings on the same ETE-S chain or on neighboring π-π stacked chains).

3. Results and Discussion

3.1 Formation of Crystallites and Percolation Paths

Given the difficulty in quantifying the concentration of the oligomer in the plant conditions and the corresponding water content in the casted films, we study the crystallization of ETE-S for a broad range of water contents, starting from a solution of 83% w.t and removing water step by step until reaching a dry phase as described in the Methods section. In a previous experimental work[10], it was elucidated by Liquid Chromatography-Mass Spectrometry (LC-MS) and ^{1}H-NMR spectroscopy that ETE-S can polymerize up to chain lengths of *n*=2-3 units. In the present study, we thus consider lengths of ETE-S oligomers *n*=1, 2 and 3. In its pristine state (i.e. as polymerized), each oligomer is oxidized, i.e. positively charged polarons (usually referred to as radical cations in the chemical nomenclature) are generated in the backbone of the ETE-S chains. The oxidation is produced via self-doping where positive charges in the backbone are compensated by negative charges on the sulfonic groups SO_3^- to maintain the charge neutrality of the oligomer. In the pristine state the oxidation level of the self-doped ETE-S is 33% i.e. one positive charge per three rings of the backbone. The charge distribution for an oligomer of *n*=3 units is illustrated in Figure S1.

Please do not adjust margins

Please do not adjust margins

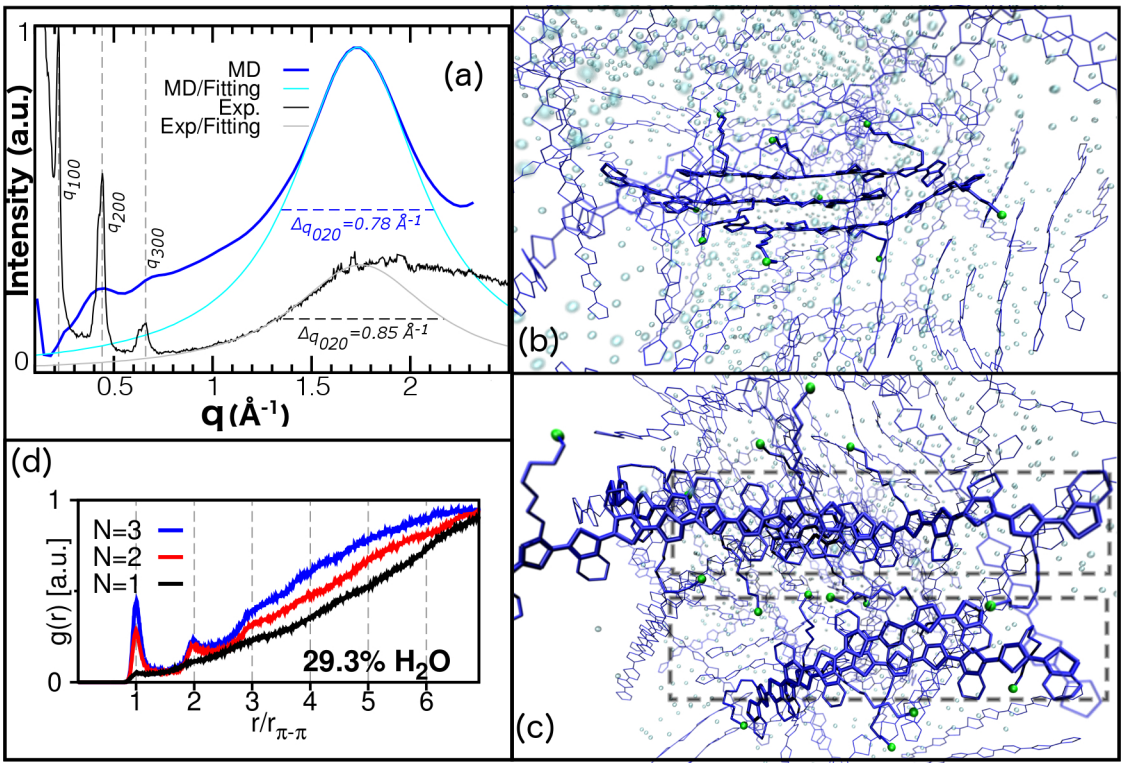

Figure 2. (a) Experimental GIWAXS pattern of the cast oligomer film cast and calculated X-ray diffraction pattern on the simulated ETE-S, n=3 at a water content of 29.3 % w.t. **(d)** Radial distribution function between oligomer chains with n=1,2 and 3. **(b)-(c)** The production snapshot with n=3 from *side* and *top* view, respectively. ETE-S chains are represented in blue, sulfonate groups are illustrated by the S atom in green and water molecules by O atoms in light blue. H atoms are not shown. Rectangular boxes in (c) show two neighboring crystallites outlining the formation of lamellar structure.

Figures 1a-c show typical structure conformations of ETE-S in solution. Only the snapshots corresponding to a solvent content of 29.3 % w.t. are shown for clarity. For the ETE-S monomers (n=1) there is not any evidence of formation of π-π stacking (Figure 1a), whereas ETE-S dimers and trimers (n= 2 and 3 respectively) exhibit a formation of small crystallites due to the π-π stacking of the chains with a stacking distance $r_{\pi\pi}$=3.5Å, see Figures 1b-c. Visual inspection of production snapshots for different water content shows that the crystallites typically consist of two or three π-π stacked oligomers. This is confirmed by the calculation of the radial distribution function $g(r)$ for the distance between ETE-S chains, see Figure 2d. For ETE-S dimer and trimers the radial distribution $g(r)$ exhibits peaks at $r/r_{\pi\text{-}\pi}$=1,2, which corresponds to crystallites consisting of two and three chains respectively. Note that $g(r)$ does not show any peaks for ETE-S monomers.

It has been experimentally demonstrated that xylem wires filled with in-vivo polymerized ETE-S show a rather high conductivity (in the range of 10 S/cm)[10]. In conducting polymers charge transport is caused by phonon-assisted hopping between or along the chains when charge carriers follow percolative paths through the system[40]. It is therefore of interest to study the formation of the percolative paths in the system at hand. Figure 1b-c shows representative percolative paths for ETE-S dimers and trimers. Note that percolative paths are absent in ETE-S monomers, see Figure 1a. (The percolative paths are defined as those where charge carriers can jump along the backbone of the same oligomer chain or between neighboring π–π stacked chains[23]). For dimers and trimers, the percolative paths include both crystallites and oligomers not belonging to crystallites. The latter provide the linkage between different crystallites, which gives rise to the percolative paths that extend throughout the whole structure, despite the fact that the crystallites are small and consist of only two or three oligomers. Our calculations showing the existence of the percolative paths explain the observed high conductivity in in-vivo polymerized ETE-S[10]. It is noteworthy that our

Please do not adjust margins

Please do not adjust margins

simulations are also consistent with previous experimental findings where it was argued that good crystallinity is not necessary for high conductivity in conducting polymers provided the linkage between the individual polymeric chains leads to the formation of percolation paths in the system[41-43].

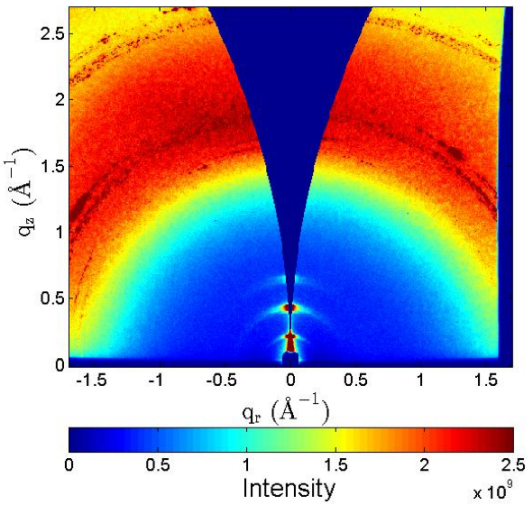

Figure 3 2D GIWAXS image of a film of trimer that has been polymerized from solution

3.2 Structural Characterization

GIWAXS measurements have been conducted to elucidate the structure of the polymerized ETE-S oligomer. The (q_r, q_z) 2D scattering pattern of the solution-cast film is presented in Figure 3. Anisotropical scattering is observed with three well-apparent diffraction peaks apparent along the near out-of-plane direction q_z (where $q_r \approx 0$). These peaks testify the presence of crystallites in the film. In order to further study the properties of these crystallites, the 1D *Intensity* vs q scattering pattern was derived and is presented in Figure 2a. Based on this, the maximum intensities of the diffraction peaks are located at q=0.22 Å^{-1}, 0.44 Å^{-1} and 0.66 A^{-1}. The relative position of these peaks (q^*, $2q^*$, $3q^*$) and their decreasing intensity suggest that they belong to the same family of reflections and that they correspond to an ordered lamellar structure. Following the interpretation by Aasmundtveit *et al.* [44], we assign these peaks to the h00 family of reflections of the oligomer crystallites, the h00 direction being perpendicular to the trimers backbone (c-axis) and along the EDOT direction (alternatively, along the aliphatic side chain direction). Therefore, the corresponding lattice size is $\alpha = 2\pi/q^* = 28.5$Å. This size is big enough to commensurate the length of the two aliphatic chains that are extended on both sides of the backbone, *i.e.* the SO_3^- - SO_3^- distance as depicted in Figures 1b-c. In fact, a closer look at the data shows that the 200 and 300 peaks can be deconvoluted in three peaks, located at 0.4 Å^{-1},0.42 Å^{-1} and 0.44 Å^{-1} respectively, as far as the 200 peak is concerned (See Figure S2 for details in an enlarged scale). Their close vicinity and the limited resolution at the low q's inhibit their deconvolution for the 100 peak. These could be suggestive of a slight disorder of the crystalline structure.

Besides the h00 family, a broad peak is present at around q=1.8 Å^{-1}. The peak position and width are reminiscent of diffraction that arises from a quite disordered π-π stacking. Therefore, it can be assigned to the 020 peak[44]. In order to extract the crystallite size L in the π-π stacking direction the Sherrer's equation[45] is used,

$$L_{020} = \frac{2\pi K}{\Delta q_{020}}, \quad (1)$$

where $K \approx 0.93$ is the shape factor and Δq_{020} is the full width at half maximum of the 020 peak. To extract Δq_{020} the Lorentz fitting was applied to the 020 peak to fit the left side of the peak since its right side is associated to parasitic/background scattering, see Figure 2a. This gives Δq_{020}=0.85 Å^{-1} which according to Eq. (1) corresponds to the crystallite size L_{020}=7.4Å, i.e. to three chains packed along the π-π stacking.

The experimental GIWAXS characterization of the ETE-S film is consistent by the results of MD simulations of the X-ray diffraction pattern. The X-ray diffraction pattern of conducting polymers is sensitive to the water content as demonstrated in ref.[23] for the case of a doped PEDOT. Thus, we calculated the X-ray diffraction pattern for each water evaporation step to match the experimental GIWAXS pattern, see Figure S3. Figure 2a shows the calculated X-ray diffraction pattern for ETE-S trimers with water content of 29.3 % w.t. where the best agreement in the peak width with the experimental pattern is found. The fitting of the main peak at q=1.8 Å^{-1} (corresponding to the π-π stacking) gives the full width at the half maximum Δq_{020}=0.78 Å^{-1}. According to Eq. (1) this corresponds to a crystallize size L_{020}=8.1Å, which matches very well the experimental value L_{020}=7.4Å extracted from the GIWAXS measurements. It is noteworthy that the calculated crystallite size L_{020}=8.1Å (corresponding to three chains in the π-π stacking) is fully consistent with the corresponding result obtained in Sec. 3.1 from the analysis of the distribution function $g(r)$ for the distance between ETE-S chains (Figure 2d).

Please do not adjust margins

Please do not adjust margins

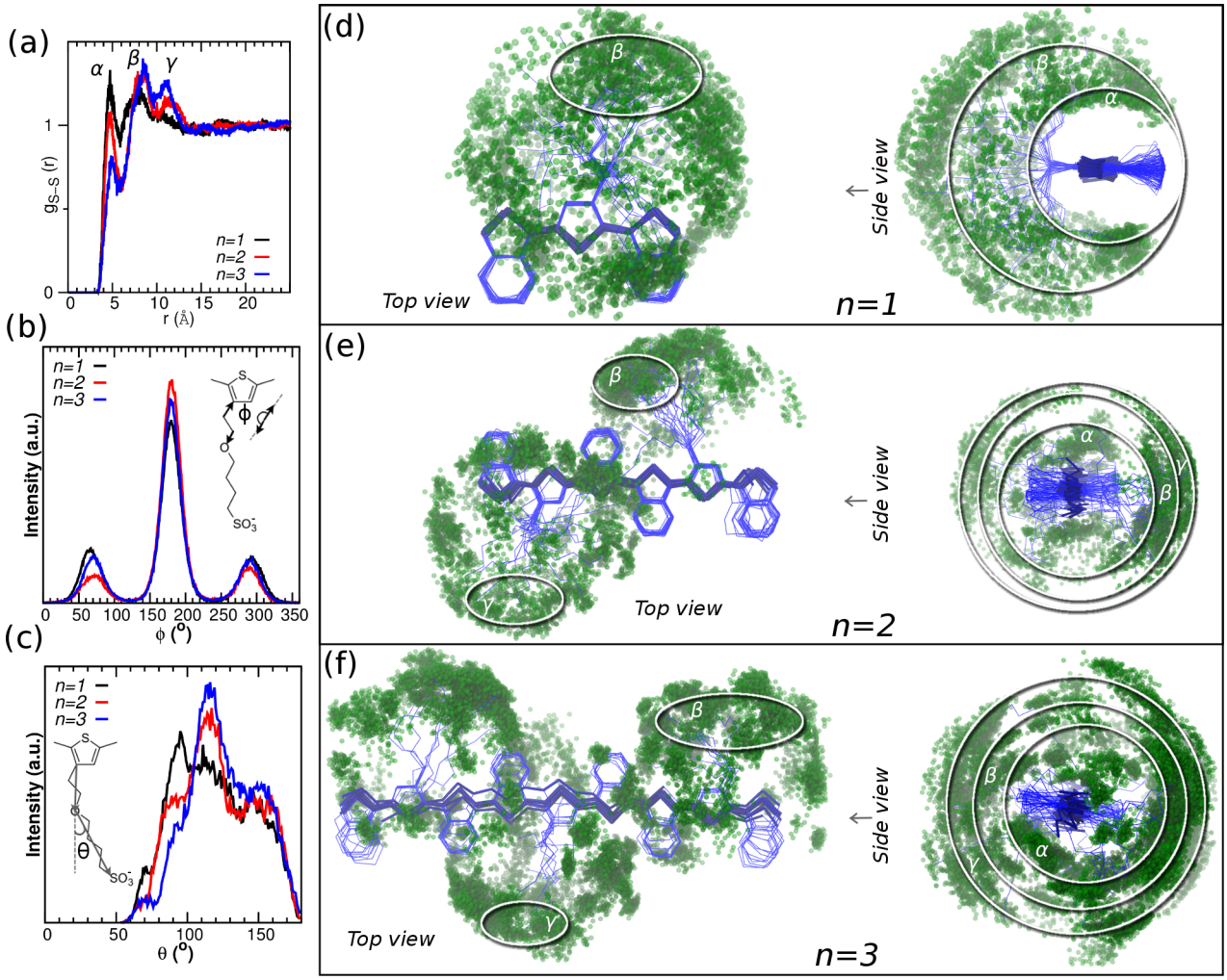

Figure 4. (a) Radial distribution function $g_{S\text{-}S}(r)$ for the distance between S from SO_3 and S from the thiophene ring for different chain lengths, *n*. (b) Probability distribution function, $P(\phi)$ and definition of dihedral angle between neighbouring atoms in the aliphatic chain, ϕ. (c) Probability distribution function, $P(\theta)$ and definition of the angles between aryl-C, ether-O and sulfonate-S, θ. (d)-(f) Folding of sulfonates groups (green spheres) on the plane of ETE-S chains (blue) is visualized by plotting them with their thiophene rings aligned; chain lengths *n*= 1, 2, 3 respectively; water content is 29% w/w. No hydrogen atoms are showed. Circles and ellipses indicate the corresponding location of the SO_3 groups given by peaks *α*, *β*, *γ* in the distribution function $g_{S\text{-}S}(r)$ in (a).

In addition to the main peak at q = 1.8 Å^{-1} the calculated diffraction pattern of ETE-S trimer exhibits three weak and broad peaks, located at q-values that agree well with the experimentally observed h00 peaks ($q \approx$ 0.25 Å^{-1}, 0.44 Å^{-1} and 0.66 A^{-1}). Therefore, we attribute these peaks to the formation of a lamellar structure along the a-axis (h00) direction, created by the aliphatic side chains, in consistence with the experimental results. This lamellar structure is well apparent in Figure 2c which shows the production snapshots of the ETE-S trimer structure. The organization of the crystallites into lamellae is illustrated by dashed squares. According to the snapshot, two lamellae are separated by a lamellar-d spacing ≈ 14Å along the aliphatic side chain direction. This spacing is half with respect to the α-lattice size of 28.5Å that was calculated based on the experimental 100 diffraction peak. Yet it corresponds well to the d-spacing that is calculated based on the peak at $q \approx$ 0.4 Å^{-1} on the calculated diffraction pattern (Figure 2a). We note that this later peak is more intense with respect to the calculated peak at $q \approx$ 0.25 Å^{-1} which corresponds to the experimental 100 peak. We attribute this to the fact that the computational box used herein has a typical size of 10×10×10 nm^3, which is not big enough to reproduce the periodicity along the a-lattice direction. Moreover, the snapshot in Figure 2c reveals a significant disorder of the aliphatic chains between the two lamellae. This disorder is expressed as a broad halo between 0.3 Å^{-1} – 1 Å^{-1} in the calculated diffraction pattern, on top of which the three broad h00 peaks are superposed. Note that the molecules within the computational box are not incurred to external factors that could affect their orientation or structuration. The snapshot corresponds, thus, to a bulk material and not to a thin, confined film. However, the molecules in a real film experience additional forces thanks to their interactions with the substrate. Therefore, a preferential orientation may be adopted and an increase in order may be expected, as is the case herein; the fact that the h00 peaks lie along the near out-of-plane direction q_z (where

Please do not adjust margins

Please do not adjust margins

$q_r \approx 0$) in the GIWAXS image (Figure 3) indicates that the molecules are oriented with the aliphatic chain direction perpendicular to the substrate (edge-on orientation), in consistence with what has been already observed for PEDOT-based films. [46-48] In our calculations we do not take into account the substrate contribution and thus our calculations point towards a much less ordered system along the α-lattice direction. It is noteworthy that weak lamellar peaks in the calculated X-ray diffraction pattern (with the intensity smaller than the experimental ones) have been already reported for PEDOT:TOS[23]. Finally, we note that onset of the lamellas formation is also seen for ETE-S dimer, but it is less pronounced in comparison to the ETE-S trimer, cf. Figures S3a and S3b.

3.3 Geometry Conformation of ETE-S oligomer

In order to describe the distribution of sulfonate groups around the ETE-S chains, the radial distribution function between sulfur in SO_3^- functional group and sulfur in thiophene ring, $g_{s\text{-}s}(r)$, was calculated and plotted in Figure 4a. Also, the distribution function $P(\phi)$ for dihedral angles, ϕ, along the whole aliphatic chains (i.e an average over all bonds) was calculated as shown and defined in Figure 4b. In addition, the distribution function $P(\theta)$ for the angle θ between the thiophene ring, O-ether and the S-sulfonate (as defined in Figure 4c) was calculated. In order to visualize the bending of the aliphatic chains, we plot together all the chains in the system with their backbone atoms in thiophene rings superposed, see Figure 4d-f. This structural superposition was performed by the least-squares fitting algorithm as implemented in GROMACS suite[36], which finds an optimal rotation and translation by minimizing the sum of the squared distances among all structures in the superposition[49]. This representation provides a graphical interpretation of the radial distribution function $g_{s\text{-}s}(r)$, and distribution functions $P(\phi)$ and $P(\theta)$. The distribution $g_{s\text{-}s}(r)$ shows three main peaks at $r \approx$ 4.8-5Å (α), 8-8.5Å (β) and 11-11.5Å (γ). Figures 4d-c indicate conformations of aliphatic chains contributing to the peaks α, β and γ for ETE-S oligomers of the lengths n=1,2,3. The intensities of peaks α and γ respectively decreases and increases when n is increased. This is because crystallites contain fewer oligomers for the case of ETE-S dimers than for ETE-S trimers (Figure 3d) and therefore, sulfonates groups can fold closer to the surface of thiophene rings for the case of shorter oligomers. This behavior is consistent with the distribution of the dihedral angles $P(\phi)$, where the main central peak at ϕ=180° is lower for shorter oligomers, whereas the extra peak at ϕ=70° and its complementary at ϕ=290° are instead higher, see Figure 4b. Note that full straight aliphatic chain should generate a single peak ϕ=180°. The bending of the whole aliphatic chain at the O-ether is described by the distribution function $P(\theta)$, see Figure 4c; the bending becomes more pronounced for longer oligomers.

Finally, we note that the distribution functions $g_{s\text{-}s}(r)$, $P(\phi)$ and $P(\theta)$ are affected by the formation of lamellar structure because the sulfonic groups belonging to oligomers in one crystallite can bend over to the backbone of oligomers in a neighboring crystallite as can be seen in Figure 2c.

4. Conclusions

The recently synthesized self-doped conducting oligomer ETE-S represents a very promising material for green energy applications and bioelectronics because of its ability of *in vivo* polymerization inside living plants[10]. Improving its material properties and developing device applications require detailed understanding of the morphology of this material. In the present study, we combine theoretical modelling of ETE-S morphology using atomistic molecular dynamics simulation and its experimental characterization using GIWAXS. To the best of our knowledge our study represents the first theoretical simulation of the morphology of a self-doped conducting oligomer.

The experimental GIWAXS measurements show the formation of small crystallites composed of up to 3 π - π stacked oligomers separated by a stacking distance $r_{\pi\pi}$ = 3.5Å. The crystallites are further organized in *h00* lamellae structures. Our molecular dynamics simulations are in a good agreement with the experimental findings. In particular, the calculated X-ray diffraction pattern matches well the experimental one, and the calculated results reproduce well the π - π stacking distance, the size of crystallites and the formation of lamellar structures. Our simulations demonstrate the formation of the percolative paths that extend throughout the whole structure, despite the fact that that crystallites are small and consist of only two or three oligomers. The existence of the percolative paths explains the observed high conductivity in *in-vivo* polymerized ETE-S[10]. We also study the geometrical conformation of ETE-S oligomers and bending of their aliphatic chains depending on the oligomer lengths.

The agreement between theory and experiment demonstrates the predictive power of the molecular dynamics simulations and we hope that our results would motivate further theoretical studies of related conducting polymers.

5. Acknowledgements

This work was supported by the Swedish Energy Agency (grant 38332-1), and Knut and Alice Wallenberg Foundation (Project "The Tail of the Sun"). The computations were performed on resources provided by the Swedish National Infrastructure for Computing (SNIC) at NSC. E.S. is also supported by a Marie Sklodowska Curie Individual Fellowship (MSCA-IF-EF-ST, Trans-Plant, 702641). The ESRF and NWO are acknowledged for allocating beam time at the Dutch-Belgian beamline (DUBBLE) for the GIWAXS experiments.

Please do not adjust margins

Please do not adjust margins

6. References

1. N. K. Guimard, N. Gomez and C. E. Schmidt, *Progress in Polymer Science*, 2007, **32**, 876-921.
2. E. Stavrinidou, O. Winther-Jensen, B. S. Shekibi, V. Armel, J. Rivnay, E. Ismailova, S. Sanaur, G. G. Malliaras and B. Winther-Jensen, *Phys Chem Chem Phys*, 2014, **16**, 2275-2279.
3. S. M. Richardson-Burns, J. L. Hendricks, B. Foster, L. K. Povlich, D. H. Kim and D. C. Martin, *Biomaterials*, 2007, **28**, 1539-1552.
4. D. Khodagholy, J. N. Gelinas, Z. Zhao, M. Yeh, M. Long, J. D. Greenlee, W. Doyle, O. Devinsky and G. Buzsaki, *Science Advances*, 2016, **2**, e1601027-e1601027.
5. Z. T. Zhu, J. T. Mabeck, C. Zhu, N. C. Cady, C. A. Batt and G. G. Malliaras, *Chem Commun (Camb)*, 2004, DOI: 10.1039/b403327m, 1556-1557.
6. X. Strakosas, M. Huerta, M. J. Donahue, A. Hama, A.-M. Pappa, M. Ferro, M. Ramuz, J. Rivnay and R. M. Owens, *Journal of Applied Polymer Science*, 2017, **134**.
7. A. Jonsson, Z. Song, D. Nilsson, B. A. Meyerson, D. T. Simon, B. Linderoth and M. Berggren, *Science Advances*, 2015, **1**.
8. D. T. Simon, E. O. Gabrielsson, K. Tybrandt and M. Berggren, *Chem Rev*, 2016, **116**, 13009-13041.
9. E. Stavrinidou, R. Gabrielsson, E. Gomez, X. Crispin, O. Nilsson, D. T. Simon and M. Berggren, *Science Advances*, 2015, **1**, 1-8.
10. E. Stavrinidou, R. Gabrielsson, K. P. Nilsson, S. K. Singh, J. F. Franco-Gonzalez, A. V. Volkov, M. P. Jonsson, A. Grimoldi, M. Elgland, I. V. Zozoulenko, D. T. Simon and M. Berggren, *Proc Natl Acad Sci U S A*, 2017, **114**, 2807-2812.
11. L. Ouyang, C. L. Shaw, C. C. Kuo, A. L. Griffin and D. C. Martin, *J Neural Eng*, 2014, **11**, 026005.
12. A. V. Volkov, S. K. Singh, E. Stavrinidou, R. Gabrielsson, J. F. Franco-Gonzalez, A. Cruce, W. M. Chen, D. T. Simon, M. Berggren and I. V. Zozoulenko, *Advanced Electronic Materials*, 2017, DOI: 10.1002/aelm.201700096, 1700096.
13. J. Yue and A. J. Epstein, *Macromolecules*, 1991, **24**, 4441-4445.
14. J. Yue, Z. H. Wang, K. R. Cromack, A. J. Epstein and A. G. MacDiarmid, *Journal of the American Chemical Society*, 1991, **113**, 2665-2671.
15. J. Lee, H. Kang, S. Kee, S. H. Lee, S. Y. Jeong, G. Kim, J. Kim, S. Hong, H. Back and K. Lee, *ACS Appl Mater Interfaces*, 2016, **8**, 6144-6151.
16. K.-G. Lim, S. Ahn, H. Kim, M.-R. Choi, D. H. Huh and T.-W. Lee, *Advanced Materials Interfaces*, 2016, **3**, 1500678.
17. Y. K. Lan and C. I. Huang, *J Phys Chem B*, 2008, **112**, 14857-14862.
18. Y. K. Lan and C. I. Huang, *J Phys Chem B*, 2009, **113**, 14555-14564.
19. S. Dag and L. W. Wang, *J Phys Chem B*, 2010, **114**, 5997-6000.
20. K. Do, D. M. Huang, R. Faller and A. J. Moule, *Phys Chem Chem Phys*, 2010, **12**, 14735-14739.
21. C. Melis, L. Colombo and A. Mattoni, *The Journal of Physical Chemistry C*, 2011, **115**, 576-581.
22. K. N. Schwarz, T. W. Kee and D. M. Huang, *Nanoscale*, 2013, **5**, 2017-2027.
23. J. F. Franco-Gonzalez and I. V. Zozoulenko, *J Phys Chem B*, 2017, **121**, 4299-4307.
24. Y. S. Lin, G. D. Li, S. P. Mao and J. D. Chai, *J Chem Theory Comput*, 2013, **9**, 263-272.
25. R. Krishnan, J. S. Binkley, R. Seeger and J. A. Pople, *The Journal of Chemical Physics*, 1980, **72**, 650-654.
26. M. J. Frisch, G. W. Trucks, H. B. Schlegel, G. E. Scuseria, M. A. Robb, J. R. Cheeseman, G. Scalmani, V. Barone, G. A. Petersson, H. Nakatsuji, X. Li, M. Caricato, A. V. Marenich, J. Bloino, B. G. Janesko, R. Gomperts, B. Mennucci, H. P. Hratchian, J. V. Ortiz, A. F. Izmaylov, J. L. Sonnenberg, Williams, F. Ding, F. Lipparini, F. Egidi, J. Goings, B. Peng, A. Petrone, T. Henderson, D. Ranasinghe, V. G. Zakrzewski, J. Gao, N. Rega, G. Zheng, W. Liang, M. Hada, M. Ehara, K. Toyota, R. Fukuda, J. Hasegawa, M. Ishida, T. Nakajima, Y. Honda, O. Kitao, H. Nakai, T. Vreven, K. Throssell, J. A. Montgomery Jr., J. E. Peralta, F. Ogliaro, M. J. Bearpark, J. J. Heyd, E. N. Brothers, K. N. Kudin, V. N. Staroverov, T. A. Keith, R. Kobayashi, J. Normand, K. Raghavachari, A. P. Rendell, J. C. Burant, S. S. Iyengar, J. Tomasi, M. Cossi, J. M. Millam, M. Klene, C. Adamo, R. Cammi, J. W. Ochterski, R. L. Martin, K. Morokuma, O. Farkas, J. B. Foresman and D. J. Fox, *Journal*, 2016.
27. U. C. Singh and P. A. Kollma, *Journal of Computational Chemistry*, 1984, **5**, 129-145.
28. J. Wang, R. M. Wolf, J. W. Caldwell, P. A. Kollma and D. A. Case, *Journal of Computational Chemistry*, 2004, **25**, 1157-1174.
29. A. Jewett, Moltemplate, www.moltemplate.org, (accessed November 18, 2015).
30. S. Plimpton, *Journal of Computational Chemistry*, 1995, **117**, 1-19.
31. H. J. C. Berendsen, J. P. M. Postma, W. F. van Gunsteren and J. Hermans, in *Intermolecular Forces: Proceedings of the Fourteenth Jerusalem Symposium on Quantum Chemistry and Biochemistry Held in Jerusalem, Israel, April 13–16, 1981*, ed. B. Pullman, Springer Netherlands, Dordrecht, 1981, DOI: 10.1007/978-94-015-7658-1_21, pp. 331-342.
32. W. Shinoda, M. Shiga and M. Mikami, *Physical Review B*, 2004, **69**.
33. G. J. Martyna, D. J. Tobias and M. L. Klein, *The Journal of Chemical Physics*, 1994, **101**, 4177-4189.
34. M. Parrinello and A. Rahman, *Journal of Applied Physics*, 1981, **52**, 7182-7190.
35. M. E. Tuckerman, J. Alejandre, R. López-Rendón, A. L. Jochim and G. J. Martyna, *J Phys A: Math Gen*, 2006, **39**, 5629-5651.
36. B. Hess, C. Kutzner, D. van der Spoel and E. Lindahl, *J Chem Theory Comput*, 2008, **4**, 435-447.
37. S. P. Coleman, D. E. Spearot and L. Capolungo, *Modelling and Simulation in Materials Science and Engineering*, 2013, **21**, 055020.
38. W. Bras, I. P. Dolbnya, D. Detollenaere, R. van Tol, M. Malfois, G. N. Greaves, A. J. Ryan and E. Heeley, *Journal of Applied Crystallography*, 2003, **36**, 791-794.
39. G. Renaud, R. Lazzari and F. Leroy, *Surface Science Reports*, 2009, **64**, 255-380.
40. S. D. Baranovskii, *physica status solidi (b)*, 2014, **251**, 487-525.
41. R. Noriega, J. Rivnay, K. Vandewal, F. P. Koch, N. Stingelin, P. Smith, M. F. Toney and A. Salleo, *Nat Mater*, 2013, **12**, 1038-1044.

Please do not adjust margins

Please do not adjust margins

42. X. Zhang, H. Bronstein, A. J. Kronemeijer, J. Smith, Y. Kim, R. J. Kline, L. J. Richter, T. D. Anthopoulos, H. Sirringhaus, K. Song, M. Heeney, W. Zhang, I. McCulloch and D. M. DeLongchamp, *Nat Commun*, 2013, **4**, 2238.
43. S. Wang, S. Fabiano, S. Himmelberger, S. Puzinas, X. Crispin, A. Salleo and M. Berggren, *Proc Natl Acad Sci U S A*, 2015, **112**, 10599-10604.
44. K. E. Aasmundtveit, E. J. Samuelsen, L. A. A. Petterson, O. Inganäs, T. Johansson and R. Feidenhans, *Synthetic Metals*, 1999, **101**, 561-564.
45. D. M. Smilgies, *J Appl Crystallogr*, 2009, **42**, 1030-1034.
46. L. Viani, C. Risko, M. F. Toney, D. W. Breiby and J. L. Bredas, *ACS Nano*, 2014, **8**, 690-700.
47. A. Ugur, F. Katmis, M. Li, L. Wu, Y. Zhu, K. K. Varanasi and K. K. Gleason, *Adv Mater*, 2015, **27**, 4604-4610.
48. I. Petsagkourakis, E. Pavlopoulou, G. Portale, B. A. Kuropatwa, S. Dilhaire, G. Fleury and G. Hadziioannou, *Sci Rep*, 2016, **6**, 30501.
49. A. D. McLachlan, *Acta Crystallographic Section A*, 1982, **A38**, 871-873.

Please do not adjust margins